

HD3SS0001 SLAS827 –SEPTEMBER 2013

10.3Gbps Thunderbolt[™] Port and DisplayPort[™] Switch

Check for Samples: HD3SS0001

FEATURES

- Compatible with Thunderbolt[™] Technology Electrical Standards and DisplayPort [™]1.2a
- Wide –3dB Differential Bandwidth of Over 10GHz on 10G Path
- Supports DP and DP++ Configurations
- Handles HPD (5V tolerant) and Cable Detect
- Supports AUX and DDC MUX
- Excellent Dynamic Characteristics (on 10G path, typical values at 5GHz):
 - Crosstalk = –35dB
 - Off-Isolation = -24dB
 - Insertion Loss = –1.5dB
 - Return Loss = –20dB
 - Intra-pair Skew Added < 4ps
- Single 3.3V Power Supply
- Small 3x3mm 24-Pin QFN Package
- Low Power Consumption
 - 3.3mW Typical Active Power
 - 80 μW Typical Detect Mode

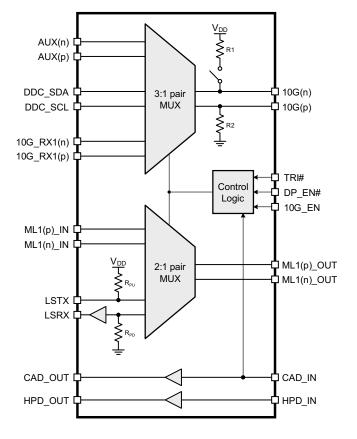
DESCRIPTION

The HD3SS0001 is a high-speed passive-switch device with integrated buffers and resistors, designed to support Thunderbolt[™] technology, DisplayPort, and Dual Mode DisplayPort. The 10G path supports a high 10GHz bandwidth and excellent loss characteristics, while the DisplayPort path supports 5.4Gbps.

The integrated 3-pairs to 1-pair multiplexer (3:1 MUX) switches between DDC, AUX, and 10.3Gbps signals. The integrated 2-pairs to 1-pair multiplexer (2:1 MUX) switches between the Thunderbolt[™] technology Low Speed UART transmit/receive pair and DisplayPort Main Link 1.

The MUXs are controlled by 4 input pins: TRI#, DP_EN#, 10G_EN, and CAD_IN (cable detect from the connector). The HD3SS0001 is packaged in a small 3x3mm 24-pin QFN, operates from a single 3.3V supply, and supports an ambient temperature range of -40°C to 85°C.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. Thunderbolt is a trademark of Intel Corp.

DisplayPort is a trademark of VESA Standards Association.

HD3SS0001

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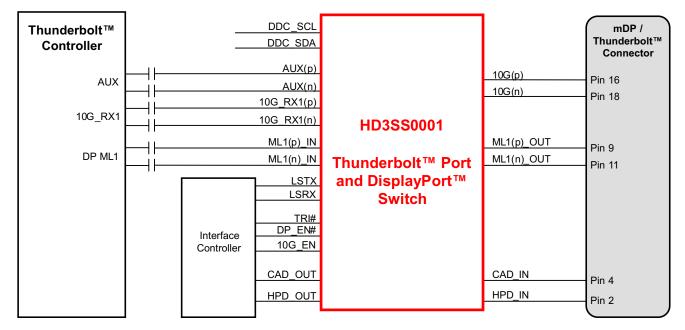
TEXAS INSTRUMENTS

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

TYPICAL APPLICATION



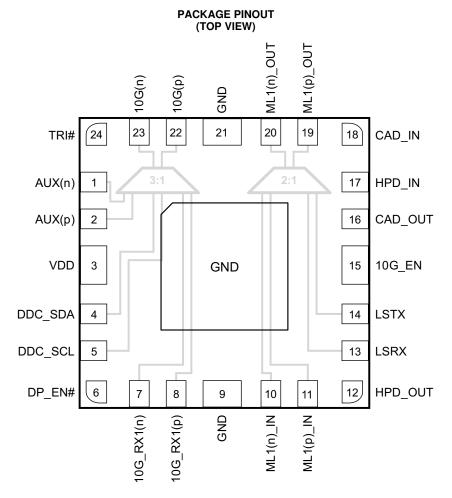
TRUTH TABLE

		LOGICAL II	NPUT TO SE	T ⁽¹⁾	EFFECT				
MODE	TRI#	DP_EN#	10G_EN	CAD_IN	2:1 MUX SELECTION ⁽²⁾	3:1 MUX SELECTION ⁽²⁾	PULL-UP RESISTOR on 10G(n)		
Thunderbolt™	1	1	1	Х	LS	10G	Disconnected		
Protocol	0	1	1	Х	LS	Tri-stated	Disconnected		
Disales Dest	1	0	0	0	ML	AUX	Connected		
DisplayPort	0	0	0	0	Tri-Stated	Tri-stated	Connected		
THE	1	0	0	1	ML	DDC	Connected		
TMDS	0	0	0	1	Tri-Stated	Tri-stated	Connected		
Detect Mode	Х	1	0	Х	LS	Tri-Stated	Connected		
[Invalid]	Х	0	1	Х	Tri-Stated	Tri-Stated	Disconnected		

(1) "X" = Don't Care.

(2) MUX Selection names are abbreviated.





MUX PIN MAPPING⁽¹⁾

CONTROLLER-SIDE PIN	Connector-Side Pin
AUX(n)	
DDC_SDA	10G(n)
10G_RX1(n)	
AUX(p)	
DDC_SCL	10G(p)
10G_RX1(p)	
ML1(p)_IN	
LSTX	ML1(p)_OUT
ML1(n)_IN	
LSRX	ML1(n)_OUT

(1) NOTE: The HD3SS0001 can tolerate polarity inversions for the differential signals denoted by the (p) and (n) terminology, to ease potential board routing issues. LSTX/LSRX cannot be swapped, since LSRX is buffered and therefore unidirectional. Also, note that the integrated pullup on 10G(n) and the integrated pulldown on 10G(p) cannot be swapped. HD3SS0001

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PIN	FUN	ICT	IONS

	DIN			
NO.	PIN NAME	- I/O	SYSTEM SIDE	DESCRIPTION
11	ML1(p)_IN			DisplayPort MainLink1(p) input
10	ML1(n)_IN			DisplayPort MainLink1(n) input
24	TRI#		Controller	Tri-State control (see TRUTH TABLE)
6	DP_EN#	I		DisplayPort Enable, active-low (see TRUTH TABLE)
15	10G_EN			10.3Gbps Mode Enable (see TRUTH TABLE)
18	CAD_IN		0	Cable Detect
17	HPD_IN		Connector	Hot Plug Detect
2	AUX(p)			AUX Positive Signal
1	AUX(n)		Controller	AUX Negative Signal
5	DDC_SCL	- I/O		DDC Clock
4	DDC_SDA			DDC Data
14	LSTX			UART TX Signal
13	LSRX			UART RX Signal
22	10G(p)			10G_RX1(p) or AUX(p) or DDC_SCL, with pull-down
23	10G(n)		Commenter	10G_RX1(n) or AUX(n) or DDC_SDA, with pull-up
19	ML1(p)_OUT		Connector	DisplayPort MainLink1(p) output or LSTX
20	ML1(n)_OUT			DisplayPort MainLink1(n) output or LSRX
8	10G_RX1(p)			10.3Gbps Positive Signal
7	10G_RX1(n)	0		10.3Gbps Negative Signal
16	CAD_OUT	0		Cable Detect
12	HPD_OUT		Controller	Hot Plug Detect
3	V _{DD}	D]	Power supply
9, 21, Center Pad	GND	Power Supply		Reference ground

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range (unless otherwise noted)

		VA	LUE	UNIT	
		MIN	МАХ		
Supply voltage range ⁽²⁾	V _{DD}	-0.5	4	V	
Voltage range	Differential I/O	-0.5	4	V	
vollage range	Control pin/buffers	-0.5	V _{DD} +0.5	v	
Control pin/butters Human body model ⁽³⁾	Human body model ⁽³⁾		±1,500	V	
Electrostatic discharge	$\begin{tabular}{ c c c c c } \hline MIN $MAX $& MIN $MAX $& V \\ \hline V_{DD} & -0.5 4 V \\ \hline Differential I/O $& -0.5 4 V \\ \hline C ontrol pin/buffers $& -0.5 V_{DD}+$0.5 $& V \\ \hline U Human body model$^{(3)} $& \pm1,500 $& \pm1,500 $& V \\ \hline C harged-device model$^{(4)} $& \pm500 $& \pm500 $& \pm1,500 $& V \\ \hline V & \pm500 $& \pm1,500 $& U \\ \hline V & \pm500 $& \pm1,500 $& U \\ \hline V & U & $$				
Continuous power dissipation	n	See Pow	See Power Characteristics		

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltage values, except differential voltages, are with respect to network ground terminal.

(2)

(3) Tested in accordance with JEDEC/ESDA JS-001-2011

(4) Tested in accordance with JEDEC JESD22 C101-E



THERMAL INFORMATION

over operating free-air temperature range (unless otherwise noted)

	THERMAL METRIC ⁽¹⁾	HD3SS0001	
		24-PIN VQFN (RLL)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	41.5	
θ _{JCtop}	Junction-to-case (top) thermal resistance	43.1	
θ _{JCbot}	Junction-to-case (bottom) thermal resistance	6.3	00.000
θ_{JB}	Junction-to-board thermal resistance	11.2	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	1.2	
Ψ_{JB}	Junction-to-board characterization parameter	11.2	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

POWER CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX ⁽¹⁾	UNIT
I _{DD}	Supply Current in Active Mode	Outputs Floating		1.0	1.3	mA
IDETECT	Supply Current in Detect Mode	DP_EN# = 1, 10G_EN = 0		26	50	μA
PD	Power Dissipation in Active Mode			3.3	4.7	mW
P _{Detect}	Power Dissipation in Detect Mode			80	150	μW

(1) The maximum ratings are simulated for $V_{DD} = 3.6V$.

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RECOMMENDED OPERATING CONDITIONS

Typical values for all parameters are at V_{DD} = 3.3V and T_A = 25°C. (Temperature limits are specified by design)

	PARAMETER	NOTES/CONDITIONS	MIN	TYP	MAX	UNIT
V _{DD}	Supply voltage		3.0	3.3	3.6 ⁽¹⁾	V
T _A	Operating free-air temperature		-40		85	°C
V	land high colleges	CAD_IN, HPD_IN ⁽²⁾ , TRI#, DP_EN#, and 10G_EN	2.0		V_{DD}	V
V _{IH} Input high voltage		ML1(n)_OUT (when 2:1 MUX selects LS)	2.0		V_{DD}	v
V	lanut law valtage	CAD_IN, HPD_IN ⁽²⁾ , TRI#, DP_EN#, and 10G_EN	-0.1		0.8	V
V _{IL}	Input low voltage	ML1(n)_OUT (when 2:1 MUX selects LS)	-0.1		0.8	v
V	Output high voltage	CAD_OUT, HPD_OUT	2.7		V_{DD}	V
V _{OH}	Output high voltage	LSRX (when 2:1 MUX selects LS)	2.7		$V_{DD}^{(1)}$	v
V		CAD_OUT, HPD_OUT	0.0		0.1	V
V _{OL}	Output low voltage	LSRX (when 2:1 MUX selects LS)	0.0		0.1	v
	High lovel input ourrent	TRI#, DP_EN#, 10G_EN, CAD_IN, and HPD_IN; $V_{DD} = 3.6V, V_{IN} = V_{DD}$			5	
I _{IH}	High-level input current	ML1(n)_OUT; V_DD = 3.6V; V_IN = V_DD (when 2:1 MUX selects LS)			3.75	μA
1	Low-level input current	TRI#, DP_EN#, 10G_EN, CAD_IN, and HPD_IN; $V_{DD} = 3.6V, V_{IN} = GND$			100	nA
I _{IL}	Low-level input current	ML1(n)_OUT; V_{DD} = 3.6V, V_{IN} = GND (when 2:1 MUX selects LS)			100	ΠA
V _{I/O_Diff}	Differential I/O voltage	AUX(p)/AUX(n), 10G_RX1(p)/ 10G_RX1(n), ML1(p)_IN/ML1(n)_IN, 10G(p)/10G(n), and ML1(p)_OUT/ML1(n)_OUT when MUX's are connected to Differential Signals.	0		1.8	Vpp
V _{I/O_CM}	Common mode I/O voltage	AUX(p)/AUX(n), 10G_RX1(p)/10G_RX1(n), ML1(p)_IN/ML1(n)_IN, 10G(p)/ 10G(n), and ML1(p)_OUT/ML1(n)_OUT when MUX's are connected to Differential Signals.	0		2.0	V

V_{DD} range supports 3.0V to 3.6V, but for Thunderbolt products it is anticipated that the V_{DD} must be maintained at less than or equal to 3.4V to ensure that the V_{OH} on the LSRx do not exceed 3.4V.

(2) HPD_IN is 5V tolerant.

ELECTRICAL CHARACTERISTICS

(under recommended operation conditions)

	PARAMETER	CONDITIONS	MIN TYP M	IAX	UNIT				
Thunderbolt™ Technology 10.3Gbps Link: 10G_RX1(p), 10G_RX1(n) ⁽¹⁾									
RL	Differential Return Loss	f = 5.0 GHz	-20		dB				
IL.	Differential Insertion Loss	f = 5.0 GHz	-1.5		dB				
O _{IRR}	Differential Off Isolation	f = 5.0GHz (see Figure 3)	-24		dB				
X _{TALK}	Differential Crosstalk	f = 5.0 GHz	-35		dB				
BW	Bandwidth	-3 dB	10		GHz				
t _{PD}	Propagation Delay(from input to output)	R_{sc} and R_{L} = 50 Ω (see Figure 2)		200	ps				
T _{SKEW}	Intra-Pair Skew Added	R_{sc} and $R_{L} = 50 \Omega$ (see Figure 2)		4	ps				
C _{ON}	Outputs ON Capacitance	V _I = 0 V, Outputs Open, Switch ON	1.5		pF				
C _{OFF}	Outputs OFF Capacitance	VI = 0 V, Outputs Open Switch OFF	1		pF				
R _{ON}	Output ON resistance	$V_{DD} = 3.3 \text{ V}, \text{ I}_{O} = -15 \mu\text{A}$	7.5		Ω				
ΔR_{ON}	On resistance match between pairs of the same channel	$V_{DD} = 3.3V; I_O = -15 \ \mu A$		1	Ω				
T _{ON}	Control Line Change to MUX Output	Cas Figure 1		400					
T _{OFF}	Switched	See Figure 1		10	μs				

(1) These values apply for CAD_IN tri-stated, unless otherwise noted.



ELECTRICAL CHARACTERISTICS (continued)

(under recommended operation conditions)

	PARAMETER	CONDITIONS	MIN TYP	MAX	UNIT
Display	Port Link: ML1(p) IN, ML1(n) IN				
RL	Differential Return Loss	f = 2.7 GHz	-16		dB
<u>ւ</u>	Differential Insertion Loss	f = 2.7 GHz; V _{CM} = 0 V	-0.8		dB
O _{IRR}	Differential Off-Isolation	f = 2.7 GHz (see Figure 3)	-20		dB
XTALK	Differential Crosstalk	f = 2.7 GHz	_35		dB
BW	Differential Bandwidth	–3 dB	7		GHz
t _{PD}	Propagation Delay(from input to output)	R_{SC} and $R_L = 50 \Omega$ (see Figure 2)		200	ps
T _{SKEW}	Intra-pair Skew Added	R_{SC} and $R_L = 50 \Omega$ (see Figure 2)		4	ps
C _{ON}	Outputs ON Capacitance	VI = 0 V; Outputs Open; Switch ON	1.5		pF
C _{OFF}	Outputs OFF Capacitance	V _I = 0 V; Outputs Open; Switch OFF	1		pF
R _{ON}	Output ON resistance	$V_{DD} = 3.3 \text{ V}; I_{O} = -15 \text{ mA}; V_{CM} = 0.5 \text{ V} \text{ to } 1.5 \text{ V}; CAD_IN = 0 \text{ V}$	6	8	Ω
∆R _{ON}	On resistance match between pairs of the same channel	V_{DD} = 3.3 V; I _O = -15 mA; V _{CM} = 0.5 V to 1.5 V		1	Ω
T _{ON} T _{OFF}	Control Line Change to MUX Output Switched	See Figure 1		400 10	μs
	rbolt™ Technology Low Speed UART : I	_STX		-	
C _{ON}	Outputs ON capacitance	$V_{I} = 0 V$, Outputs Open, Switch ON	8		рF
C _{OFF}	Outputs OFF capacitance	$V_{I} = 0 V$, Outputs Open, Switch OFF	3		pF
R _{ON}	Output ON resistance	$V_{DD} = 3 \text{ V}, V_{CM} = 0 \text{ V} \text{ to } 3 \text{ V}, I_O = -1 \text{ mA}$ CAD_IN = 0 V	12	19	Ω
t _{PD}	Propagation Delay	LSTX to ML1(p)_OUT	200		ps
Display	Port: AUX(p), AUX(n)				
C _{ON}	Outputs ON Capacitance	V _I = 0 V; Outputs Open; Switch ON	6		pF
C _{OFF}	Outputs OFF Capacitance	V _I = 0 V; Outputs Open; Switch OFF	3		pF
R _{ON}	Output ON resistance	$V_{DD} = 3.3V; I_{O} = -10 \text{ mA}; \text{AUX}(p) = 0.3 \text{ V};$ AUX(n) = 3.0 V; CAD_IN = 0 V	12		Ω
ΔR _{ON}	On resistance match between pairs of the same channel	$V_{DD} = 3.3 \text{ V}; I_{O} = -10 \text{ mA};$ $V_{CM} = 0.5 \text{ V} \text{ to } 1.5 \text{ V}$		1	Ω
T _{ON}	Control line change to Mux output			40	ms
T _{OFF}	switched	See Figure 2		10	μs
-	rbolt Technology Low Speed UART : LS	RX			
C _{ON}	Outputs capacitance		3		pF
Z _O	Output impedance	V _{DD} = 3.3 V	60		Ω
t _{PD}	Propagation delay	ML1(n)_OUT to LSRX	3.2		ns
t _r	Rise Time	V _{DD} = 3 V	3		ns
t _f	Fall Time	V _{DD} = 3 V	3		ns
T _{ON}	Control line change to MUX Output			400	μs
T _{OFF}	Switched	See Figure 1		10	μs

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ELECTRICAL CHARACTERISTICS (continued)

(under i	recommended operation conditions)		1		
	PARAMETER	CONDITIONS	ΜΙΝ ΤΥ	P MAX	UNIT
Display	/Port : DDC_SCL, DDC_SDA				
C _{ON}	Outputs ON capacitance	V _I = 0 V, Outputs Open, Switch ON		9	pF
C _{OFF}	Outputs OFF capacitance	V _I = 0 V, Outputs Open, Switch OFF		3	pF
R _{ON}	Output ON resistance	$V_{DD} = 3.3 \text{ V}, I_O = -10 \text{ mA}, V_{CM} = 0.4 \text{ V}, CAD_IN = 3.3 \text{ V}$	8	30 15	Ω (
T _{ON}	Control line change to MUX output	JX output		40	
T _{OFF}	switched	See Figure 1		10) µs
UART a	and 10G MUX Outputs : LSTX/LSRX/100	a(p)/10G(n)			
R1	Integrated Pullup Resistance	10G(n) pin when in DP, TMDS, or Detect Mode	8	37 10	5 kΩ
R2	Integrated Pulldown Resistance	10G(p) pin when in DP, TMDS, or Detect Mode, or VDD = 0V	8	37 10	5 kΩ
R _{PU}	Integrated pullup resistance	LSTX	8	.7	kΩ
R _{PD}	Integrated pulldown resistance	LSRX	1	.2	MΩ

TEST DIAGRAMS

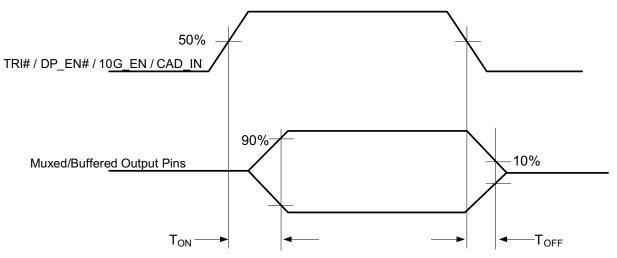
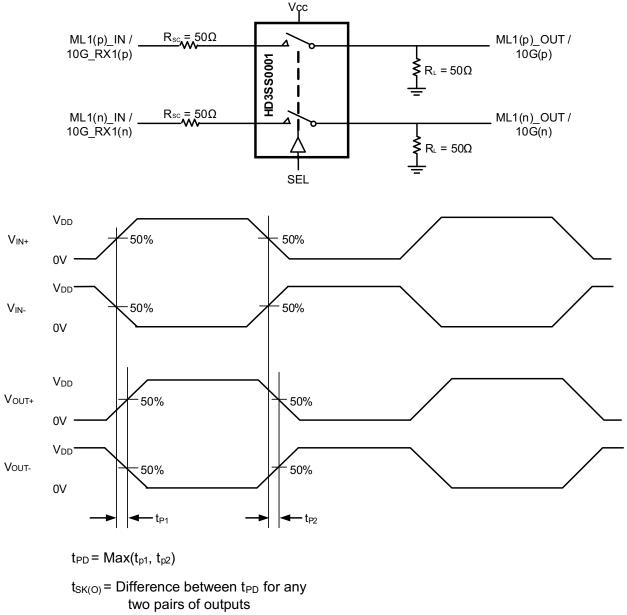


Figure 1. Control Line Change to Switched Signals





 $t_{SK(b-b)}$ = Difference between t_{P1} and t_{P2} of same pair





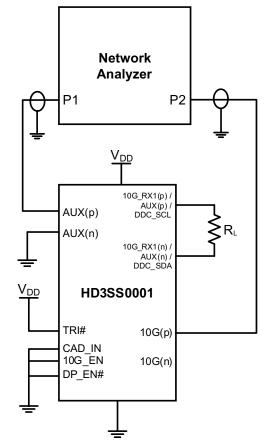


Figure 3. Off-Isolation Measurement Setup



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
HD3SS0001RLLR	ACTIVE	VQFN	RLL	24	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	3SS001	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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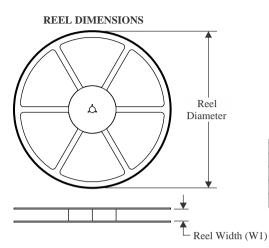
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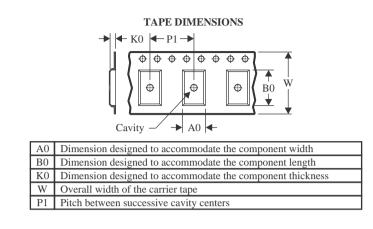


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TAPE AND REEL INFORMATION





A0

(mm)

3.3

B0

(mm)

3.3

K0

(mm)

1.1

P1

(mm)

8.0

w

(mm)

12.0

Pin1

Quadrant

Q2

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



330.0

12.4

*All dimensions are nominal						
Device	Package Type	Package Drawing	Pins	Reel Diameter		
				(mm)	W1 (mm)	

RLL

24

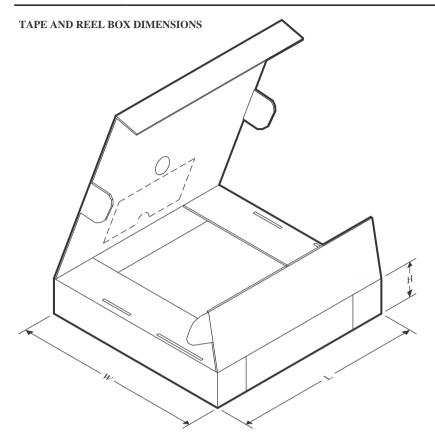
3000

VQFN



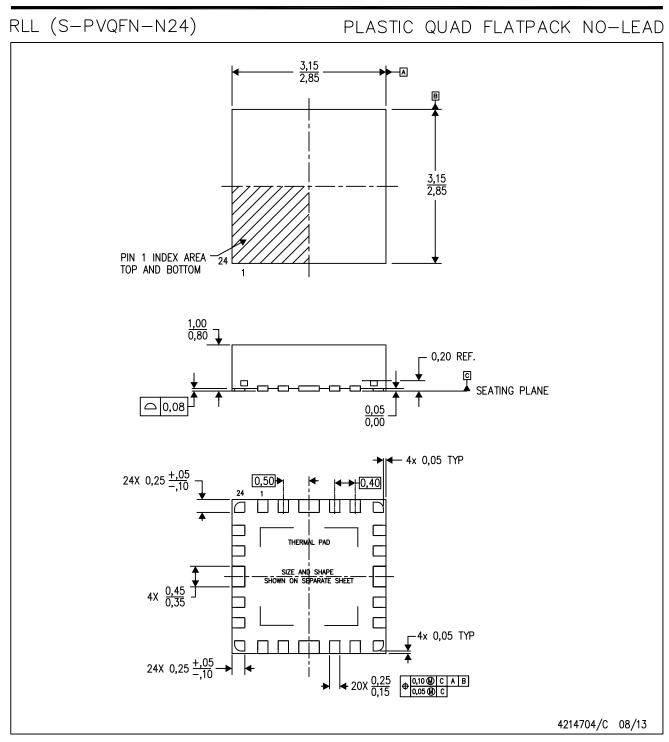
PACKAGE MATERIALS INFORMATION

20-Apr-2023



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
HD3SS0001RLLR	VQFN	RLL	24	3000	346.0	346.0	33.0



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

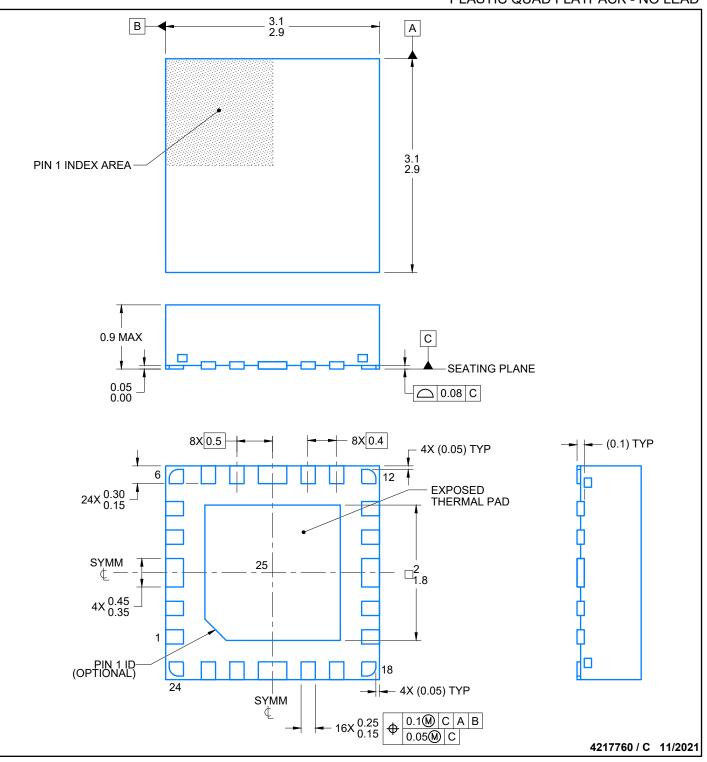
- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.



RLL0024A

PACKAGE OUTLINE VQFN - 0.9 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

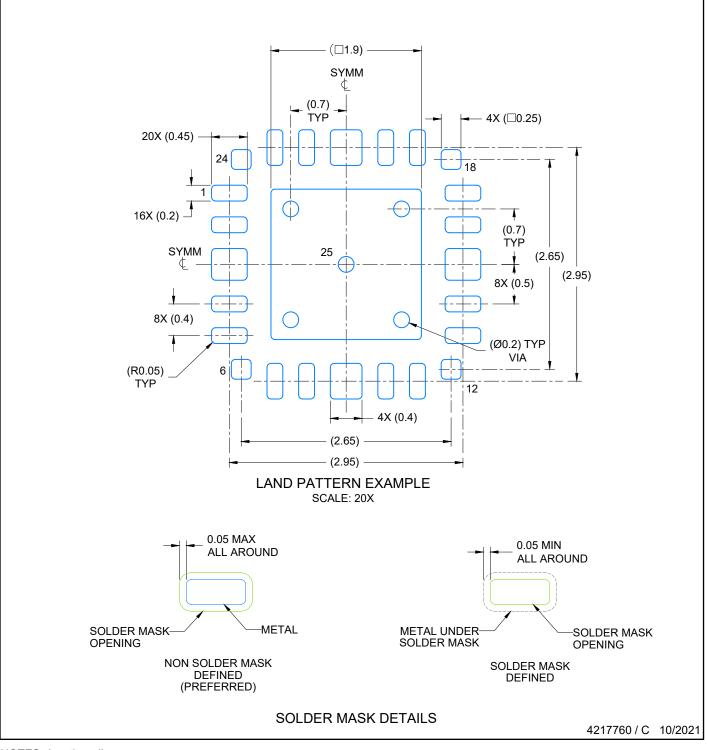
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



RLL0024A

EXAMPLE BOARD LAYOUT VQFN - 0.9 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

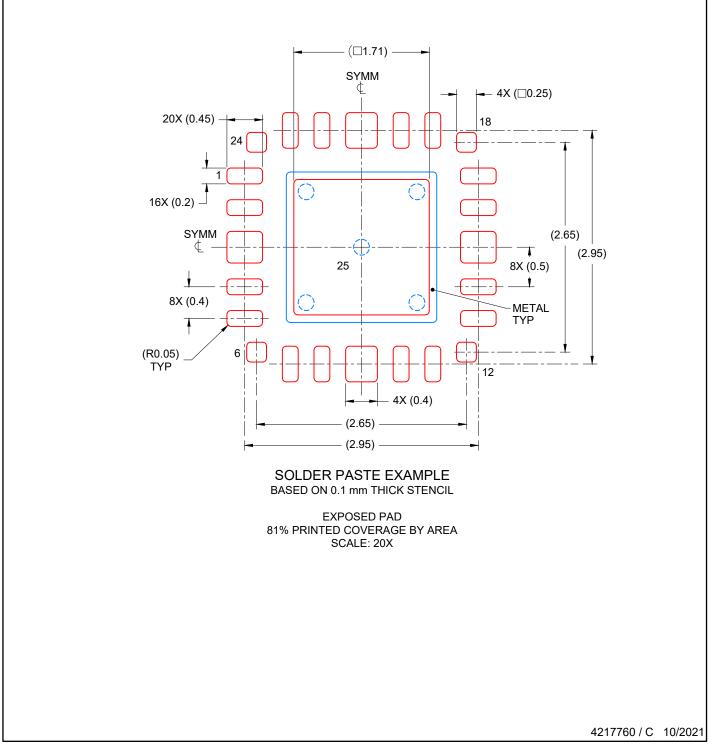
- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



RLL0024A

EXAMPLE STENCIL DESIGN VQFN - 0.9 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations..



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